BLS7G2730L-200P; BLS7G2730LS-200P LDMOS S-band radar power transistor

AMPLEON

Rev. 4 — 1 September 2015

Product data sheet

Product profile

1.1 General description

200 W LDMOS power transistor for S-band radar applications in the frequency range from 2700 MHz to 3000 MHz.

Typical performance Table 1.

Typical RF performance at $T_{case} = 25$ °C.

Test signal	f	V _{DS}	PL	Gp	η_{D}	t _r	t _f
	(GHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
Class-AB productio	n test circuit						
pulsed RF [1]	2.7 to 3.0	32	200	12	48	8	5
Application circuit							
pulsed RF [2]	2.7 to 3.0	32	220	12.5	50	20	6
pulsed RF [3]	2.9 to 3.1	32	220	12.5	50	20	6

^[1] $t_p = 300 \ \mu s; \ \delta = 10 \ \%; \ I_{Dq} = 100 \ mA$

1.2 Features and benefits

- High efficiency
- Excellent ruggedness
- Designed for broadband operation
- Excellent thermal stability
- Easy power control
- Integrated ESD protection
- High flexibility with respect to pulse formats
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

S-band radar applications in the frequency range 2700 MHz to 3000 MHz

^[2] $t_p = 3000 \,\mu s$; $\delta = 20 \,\%$; $I_{Dq} = 50 \,mA$

^[3] $t_p = 500 \,\mu\text{s}; \, \delta = 20 \,\%; \, I_{Dq} = 50 \,\text{mA}$

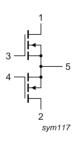
2. Pinning information

Table 2. Pinning

	9			
Pin	Description	Simplified	outline	Graphic symbol
BLS7G2730	L-200P (SOT539A)			
1	drain1			
2	drain2	1	2	1
3	gate1		5	3
4	gate2	3	4	5
5	source	[1]		4
				1 2 sym117

BLS7G2	730LS-200P (SOT539B)	
1	drain1	
2	drain2	
3	gate1	
4	gate2	
5	source	<u>[1]</u>





3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
BLS7G2730L-200P	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A	
BLS7G2730LS-200P	-	earless flanged balanced ceramic package; 4 leads	SOT539B	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V_{DS}	drain-source voltage	-	65	V
V_{GS}	gate-source voltage	-0.5	+13	V
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature	<u>[1]</u> _	225	°C

^[1] Continuous use at maximum temperature will affect the reliability.

^[1] Connected to flange.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$Z_{\text{th(j-c)}}$	n(j-c) transient thermal impedance from junction	T_{case} = 85 °C; P_L = 200 W		
	to case	t_p = 300 μ s; δ = 10 %	0.13	K/W
		$t_p = 3000 \ \mu s; \ \delta = 20 \ \%$	0.19	K/W

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.2 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 120 mA	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	22.5	-	Α
I_{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	280	nA
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 0.12 A	-	1	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 4.2 A$	-	0.13	-	Ω

Table 7. RF characteristics

Test signal: pulsed RF; $t_p = 300 \ \mu s$; $\delta = 10 \ \%$; RF performance at $V_{DS} = 32 \ V$; $I_{Dq} = 100 \ mA$; $T_{case} = 25 \ ^{\circ}C$; unless otherwise specified, in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _L = 200 W	9.8	12	-	dB
RLin	input return loss	P _L = 200 W	-	-10	-6	dB
η_{D}	drain efficiency	P _L = 200 W	43	48	-	%
P _{droop(pulse)}	pulse droop power	P _L = 200 W	-	0	0.25	dB
t _r	rise time	P _L = 200 W	-	8	50	ns
t _f	fall time	P _L = 200 W	-	5	50	ns

7. Test information

7.1 Ruggedness in class-AB operation

The BLS7G2730L-200P and BLS7G2730LS-200P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under following conditions: V_{DS} = 32 V; I_{Dq} = 100 mA; P_L = 200 W; f = 2700 MHz; t_p = 300 μ s; δ = 10 %

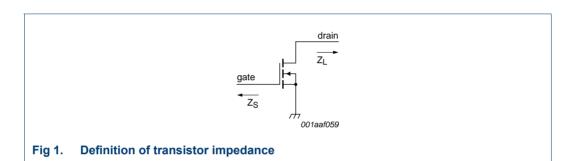
7.2 Impedance information

Table 8. Typical impedance

Measured load-pull data half device; $V_{DS} = 32 \text{ V}$; $I_{Dq} = 100 \text{ mA}$.

f	Z _S [1]	Z _L [1]
(MHz)	(Ω)	(Ω)
2700	2.0 – j5.8	3.7 – j6.4
2800	1.6 – j5.9	3.8 – j6.9
2900	2.6 – j6.2	3.8 – j6.9
3000	3.4 – j6.0	3.7 – j6.4

[1] Z_S and Z_L defined in Figure 1.



7.3 Production test circuit

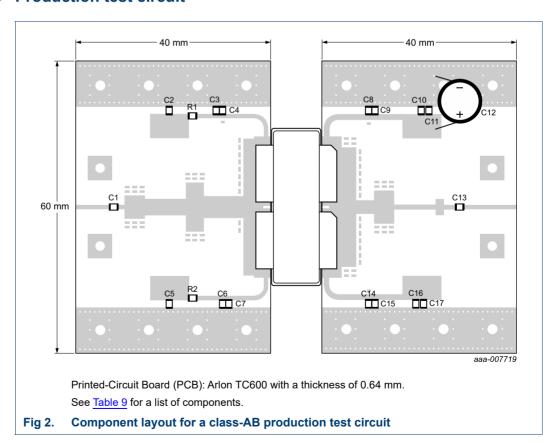


Table 9. List of components test circuit See Figure 2.

Component	Description	Value	Remarks
C1, C3, C6, C9, C13, C15	multilayer ceramic chip capacitor	18 pF	11 ATC600F
C2, C5, C10, C16	multilayer ceramic chip capacitor	1 μF	[2]
C4, C7, C8, C14	multilayer ceramic chip capacitor	12 pF	11 ATC600F
C11, C17	multilayer ceramic chip capacitor	10 μF	[2]
C12	electrolytic capacitor	2200 μF, 63 V	
R1, R2	chip resistor	9.1 Ω	[3]

- [1] American Technical Ceramics type 600F or capacitor of same quality.
- [2] Murata or capacitor of same quality.
- [3] Vishay Dale or capacitor of same quality.

7.4 Application circuit

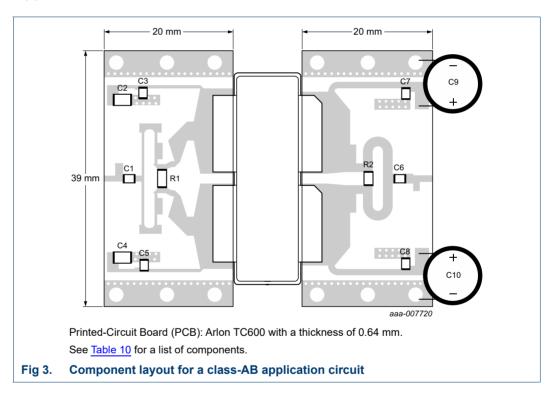


Table 10. List of components application circuit See *Figure 2*.

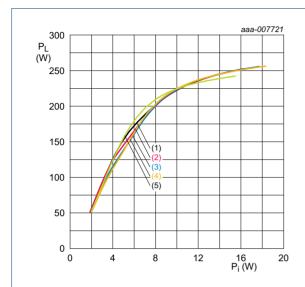
Component	Description	Value	Remarks
C1, C3, C5, C6, C7, C8	multilayer ceramic chip capacitor	12 pF	11 ATC600F
C2, C4	multilayer ceramic chip capacitor	1 μF	[2]
C9, C10	electrolytic capacitor	2200 μF, 50 V	
R1, R2	chip resistor	50 Ω	[3]

- [1] American Technical Ceramics type 600F or capacitor of same quality.
- [2] Murata or capacitor of same quality.
- [3] Vishay Dale or capacitor of same quality.

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7.5 Graphical data

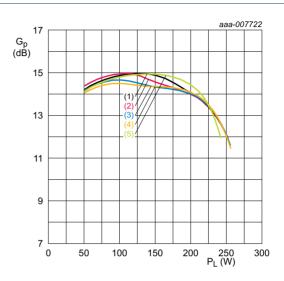
7.5.1 Test circuit



 V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 300 μ s; δ = 10 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz

Fig 4. Output power as a function of input power; typical values



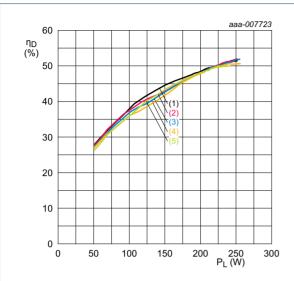
 V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 300 $\mu s; \, \delta$ = 10 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz

Fig 5. Power gain as a function of output power; typical values

BLS7G2730L(S)-200P

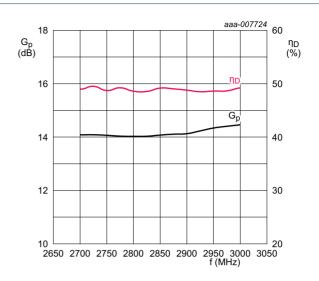
LDMOS S-band radar power transistor



 V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 300 $\mu s;$ δ = 10 %.

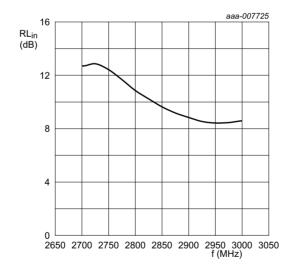
- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz





 V_{DS} = 32 V; P_L = 200 W; I_{Dq} = 100 mA; t_p = 300 $\mu s;$ δ = 10 %.

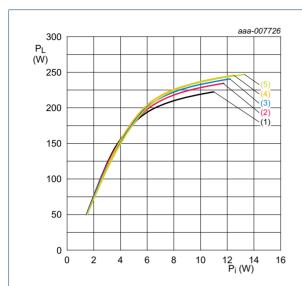
Fig 7. Power gain and drain efficiency as function of frequency; typical values



 V_{DS} = 32 V; P_L = 200 W; I_{Dq} = 100 mA; t_p = 300 $\mu s;$ δ = 10 %.

Fig 8. Input return loss as a function of frequency; typical values

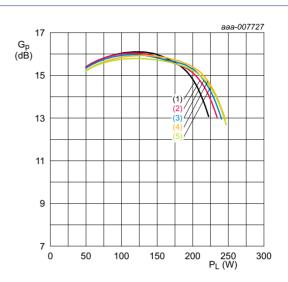
7.5.2 Application circuit



 V_{DS} = 32 V; I_{Dq} = 50 mA; t_p = 3000 μ s; δ = 20 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz

Fig 9. Output power as a function of input power; typical values



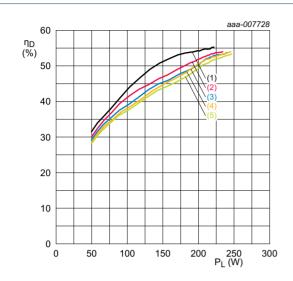
 V_{DS} = 32 V; I_{Dq} = 50 mA; t_p = 3000 μ s; δ = 20 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz

Fig 10. Power gain as a function of output power; typical values

BLS7G2730L(S)-200P

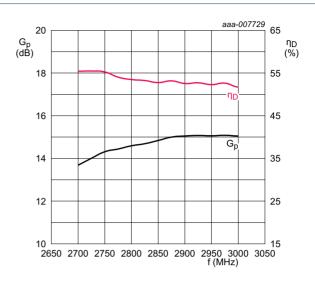
LDMOS S-band radar power transistor



 V_{DS} = 32 V; I_{Dq} = 50 mA; t_p = 3000 μ s; δ = 20 %.

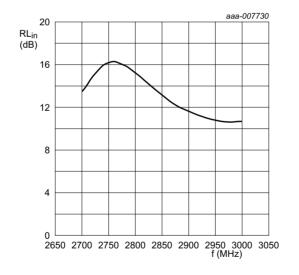
- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz





 V_{DS} = 32 V; P_L = 220 W; I_{Dq} = 50 mA; t_p = 3000 $\mu s;$ δ = 20 %.

Fig 12. Power gain and drain efficiency as function of frequency; typical values



 V_{DS} = 32 V; P_L = 220 W; I_{Dq} = 50 mA; t_p = 3000 μs ; δ = 20 %.

Fig 13. Input return loss as a function of frequency; typical values

8. Package outline

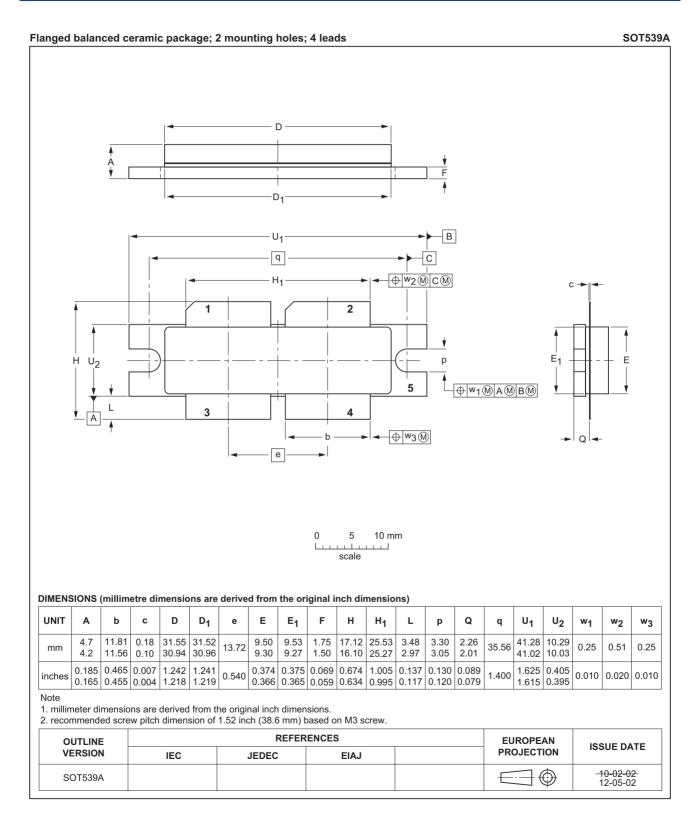


Fig 14. Package outline SOT539A

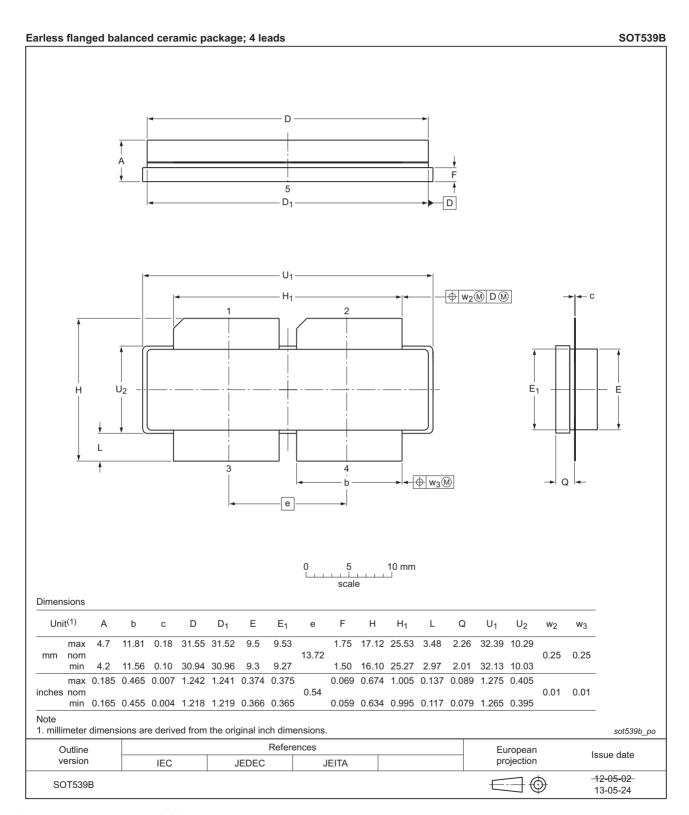


Fig 15. Package outline SOT539B

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 11. Abbreviations

Acronym	Description
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
S-band	Short wave band
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLS7G2730S-200P_LS-200P#4	20150901	Product data sheet		BLS7G2730S-200P_LS-200P v.3
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 			
BLS7G2730S-200P_LS-200P v.3	20130712	Product data sheet	-	BLS7G2730S-200P_LS-200P v.2
BLS7G2730S-200P_LS-200P v.2	20130603	Product data sheet	-	BLS7G2730S-200P_LS-200P v.1
BLS7G2730S-200P_LS-200P v.1	20130129	Objective data sheet	-	-

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Document status[1][2] Product status[3]		Definition	
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.	
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LDMOS S-band radar power transistor

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